

## T495D106K035AH40957280

T495 HRA, Tantalum, MnO2 Tantalum, HRA, 10 uF, 10%, 35 VDC, SMD, MnO2, Molded, Low ESR, High Reliability, N/A, 300 mOhms, 7343, 3.1 mm, 1.3 mm

Click here for the 3D model.

General Information	
Series	T495 HRA
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, MnO2, Molded, Low ESR, High Reliability
Features	Low ESR, High Reliability
RoHS	No
Prop 65	WARNING: Cancer and reproductive harm - https://www.p65warnings.ca.gov /
SCIP Number	1dd2e1b8-26dd-4d52-927c-6f9 d519011aa
Termination	Tin Lead (SnPb)
AEC-Q200	No
Typical Component Weight	446.84 mg
MSL	1

Dimensions	
L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
Н	2.8mm +/-0.3mm
т	0.13mm REF
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm
A	3.8mm MIN
В	0.5mm +/-0.15mm
E	3.5mm REF
G	3.5mm REF
К	1.5mm +/-0.2mm
Р	0.9mm REF
R	1mm REF
Х	0.1mm +/-0.1mm REF

Specifications	
Capacitance	10 uF
Tolerance	10%
Voltage DC	35 VDC (85C), 23.45 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	4% 120Hz 25C
Failure Rate	N/A
ESR	300 mOhms (100kHz 25C)
Ripple Current	707 mA (rms, 100kHz 25C), 636 mA (rms, 100kHz 85C), 283 mA (rms, 100kHz 125C)
Leakage Current	3.5 uA (5min 25°C)
Testing and Reliability	Tested To Meet The Established Reliability

## Packaging Specifications

Packaging	T&R, 330mm
Packaging Quantity	2500

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